NSN 5961-01-103-9699

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-103-9699 **Inclosure Material:** Metal **Overall Length:** 1.534 inches **Overall Height:** Between 0.250 inches and 0.450 inches **Overall Width:** 1.050 inches **Mounting Facility Quantity: Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 breakdown voltage, drain-to-source, with all other terminals short-circuited to source **Current Rating Per Characteristic:** 2.00 amperes zero-gate-voltage drain current **Power Rating Per Characteristic:** 25.0 watts total device dissipation **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius case **Terminal Type And Quantity:** 1 case and 2 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No